



# PDTA143/114/124/144EQB-Q series

50 V, 100 mA PNP resistor-equipped transistors

Rev. 1 — 28 September 2021

Product data sheet

## 1. General description

100 mA PNP Resistor-Equipped Transistor (RET) family in an ultra small DFN1110D-3 (SOT8015) leadless Surface-Mounted Device (SMD) plastic package with side-wettable flanks.

Table 1. Product overview

Type number	R1	R2	Package		NPN complement:
	k $\Omega$	k $\Omega$	Nexperia	JEDEC	
PDTA143EQB-Q	4.7	4.7	SOT8015	MO-340BA	PDTC143EQB-Q
PDTA114EQB-Q	10	10			PDTC114EQB-Q
PDTA124EQB-Q	22	22			PDTC124EQB-Q
PDTA144EQB-Q	47	47			PDTC144EQB-Q

## 2. Features and benefits

- 100 mA output current capability
- Built-in resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs
- Low package height of 0.5 mm
- Suitable for Automatic Optical Inspection (AOI) of solder joint
- Qualified according to AEC-Q101 and recommended for use in automotive applications

## 3. Applications

- Digital applications
- Cost saving alternative for BC857-Q series in digital applications
- Controlling IC inputs
- Switching loads

## 4. Quick reference data

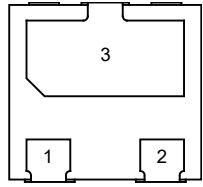
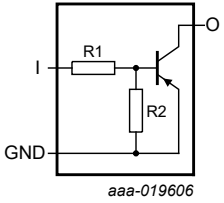
Table 2. Quick reference data

$T_{amb} = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{CEO}$	collector-emitter voltage	open base	-	-	-50	V
$I_O$	output current		-	-	-100	mA

## 5. Pinning information

Table 3. Pinning

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	I	input (base)	 <p>Transparent top view</p>	 <p>aaa-019606</p>
2	GND	GND (emitter)		
3	O	output (collector)		

## 6. Ordering information

Table 4. Ordering information

Type number	Package		
	Name	Description	Version
PDTA143EQB-Q	DFN1110D-3	plastic leadless extremely thin small outline package with side-wettable flanks (SWF); 3 terminals; 0.65 mm pitch; body: 1.1 x 1.0 x 0.48 mm	SOT8015
PDTA114EQB-Q			
PDTA124EQB-Q			
PDTA144EQB-Q			

## 7. Marking

Table 5. Marking

Type number	Marking code
PDTA143EQB-Q	D5
PDTA114EQB-Q	C8
PDTA124EQB-Q	D3
PDTA144EQB-Q	D8

## 8. Limiting values

**Table 6. Limiting values**

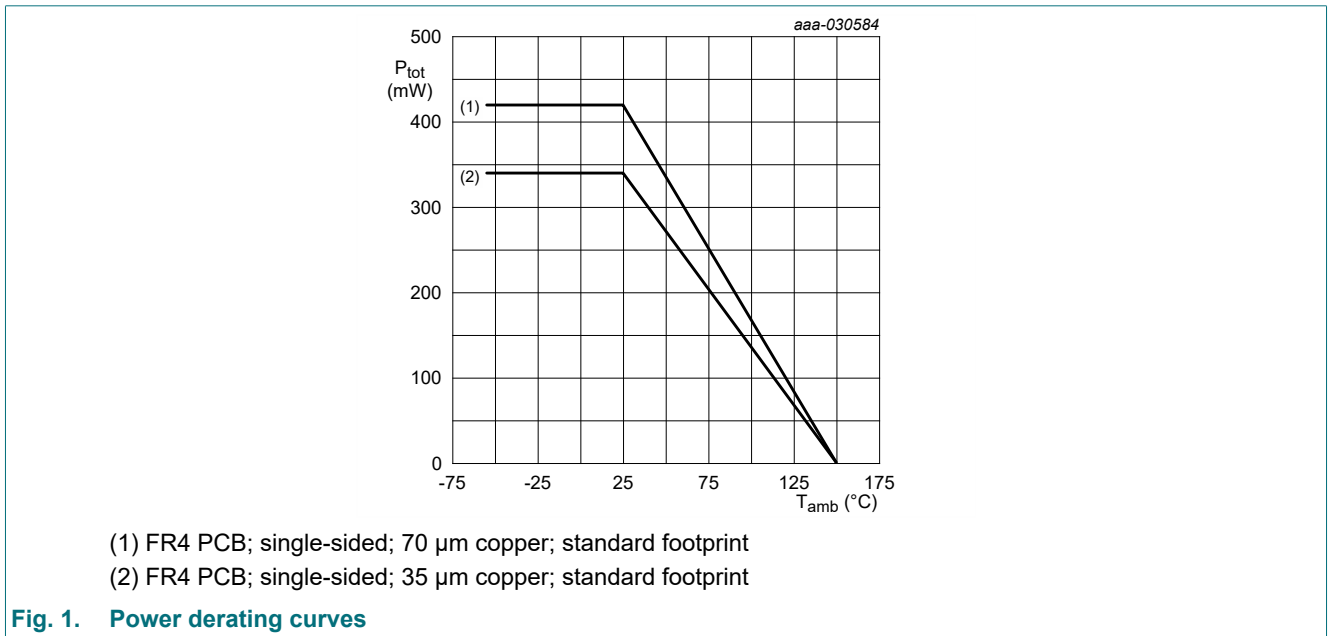
In accordance with the Absolute Maximum Rating System (IEC 60134).

$T_{amb} = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Max	Unit	
$V_{CBO}$	collector-base voltage	open emitter	-	-50	V	
$V_{CEO}$	collector-emitter voltage	open base	-	-50	V	
$V_{EBO}$	emitter-base voltage	open collector	-	-10	V	
$V_i$	input voltage					
	PDTA143EQB-Q		-30	+10	V	
	PDTA114EQB-Q		-40	+10	V	
	PDTA124EQB-Q		-40	+10	V	
	PDTA144EQB-Q		-40	+10	V	
$I_O$	output current		-	-100	mA	
$P_{tot}$	total power dissipation	$T_{amb} \leq 25\text{ °C}$	[1]	-	340	mW
			[2]	-	420	mW
$T_j$	junction temperature		-	150	°C	
$T_{amb}$	ambient temperature		-55	150	°C	
$T_{stg}$	storage temperature		-65	150	°C	

[1] Device mounted on an FR4 Printed-Circuit-Board (PCB); single-sided; 35  $\mu\text{m}$  copper; tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB; single-sided; 70  $\mu\text{m}$  copper; tin-plated and standard footprint.



**Fig. 1. Power derating curves**

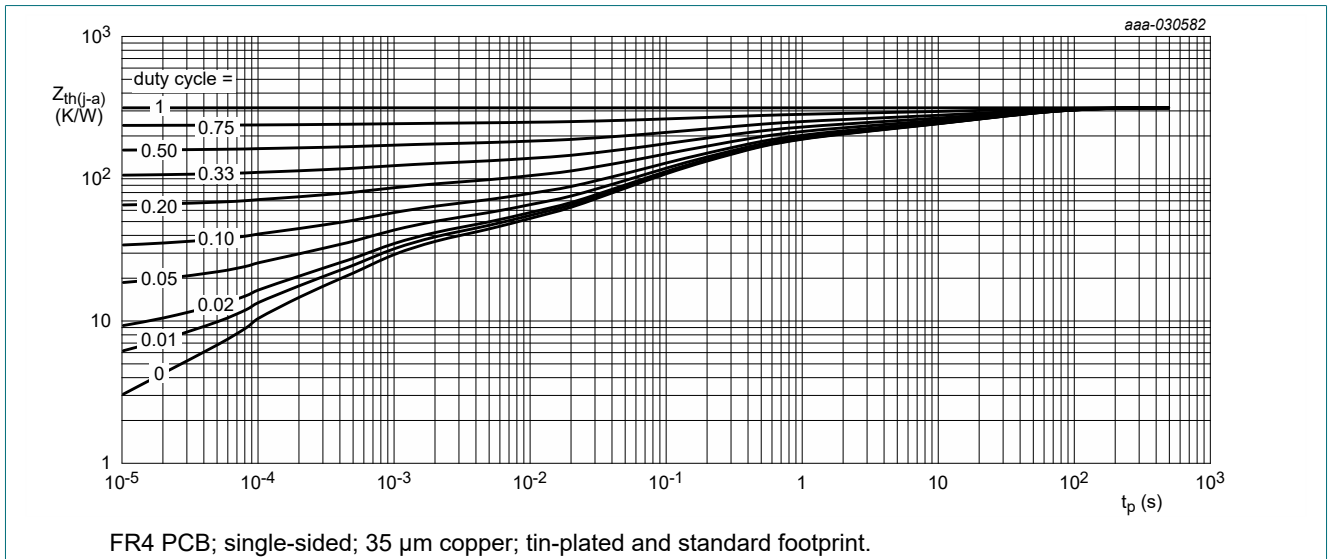
## 9. Thermal characteristics

**Table 7. Thermal characteristics**

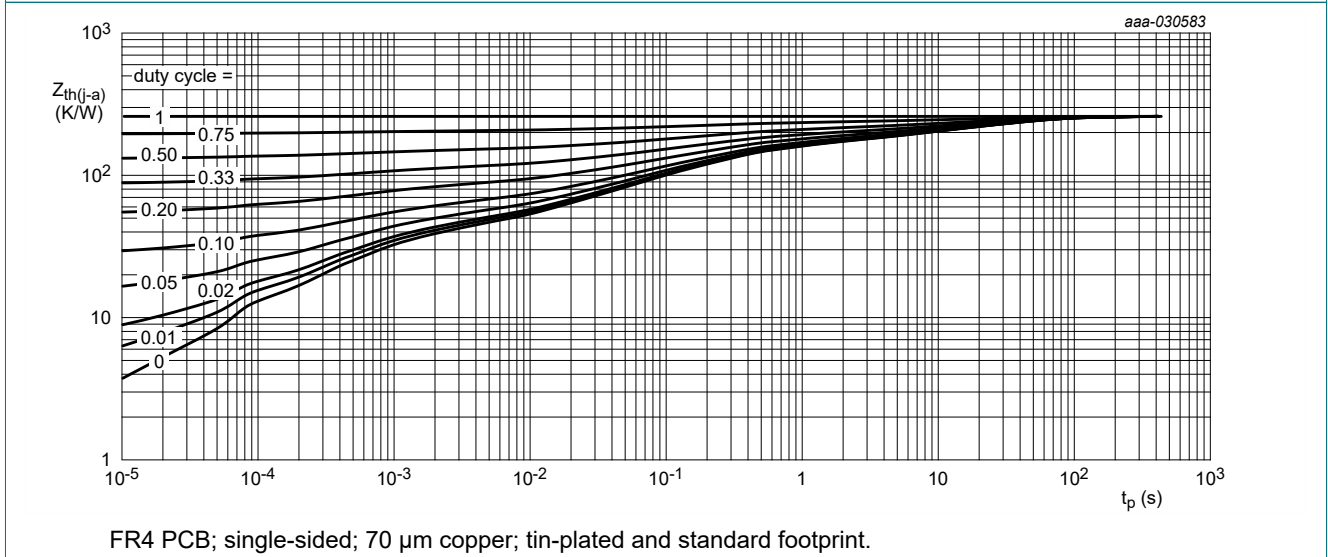
$T_{amb} = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	-	368	K/W
			[2]	-	-	298	K/W

- [1] Device mounted on an FR4 PCB; single-sided; 35  $\mu\text{m}$  copper; tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB; single-sided; 70  $\mu\text{m}$  copper; tin-plated and standard footprint.



**Fig. 2. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**



**Fig. 3. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values**

## 10. Characteristics

**Table 8. Characteristics**
 $T_{amb} = 25\text{ °C}$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit	
$V_{(BR)CBO}$	collector-base breakdown voltage	$I_C = -100\ \mu\text{A}$ ; $I_E = 0\ \text{A}$	-50	-	-	V	
$V_{(BR)CEO}$	collector-emitter breakdown voltage	$I_C = -2\ \text{mA}$ ; $I_B = 0\ \text{A}$	-50	-	-	V	
$I_{CBO}$	collector-base cut-off current	$V_{CB} = -50\ \text{V}$ ; $I_E = 0\ \text{A}$	-	-	-100	nA	
$I_{CEO}$	collector-emitter cut-off current	$V_{CE} = -30\ \text{V}$ ; $I_B = 0\ \text{A}$	-	-	-100	nA	
		$V_{CE} = -30\ \text{V}$ ; $I_B = 0\ \text{A}$ ; $T_j = 150\text{ °C}$	-	-	-5	$\mu\text{A}$	
$I_{EBO}$	emitter-base cut-off current						
	PDTA143EQB-Q	$V_{EB} = -5\ \text{V}$ ; $I_C = 0\ \text{A}$	-	-	-900	$\mu\text{A}$	
	PDTA114EQB-Q		-	-	-400	$\mu\text{A}$	
	PDTA124EQB-Q		-	-	-180	$\mu\text{A}$	
	PDTA144EQB-Q		-	-	-90	$\mu\text{A}$	
$h_{FE}$	DC current gain						
	PDTA143EQB-Q	$V_{CE} = -5\ \text{V}$ ; $I_C = -10\ \text{mA}$	30	-	-		
	PDTA114EQB-Q		30	-	-		
	PDTA124EQB-Q		60	-	-		
	PDTA144EQB-Q		80	-	-		
$V_{CEsat}$	collector-emitter saturation voltage	$I_C = -10\ \text{mA}$ ; $I_B = -0.5\ \text{mA}$	-	-	-100	mV	
$V_{I(off)}$	off-state input voltage						
	PDTA143EQB-Q	$V_{CE} = -5\ \text{V}$ ; $I_C = -100\ \mu\text{A}$	-	-1.1	-0.5	V	
	PDTA114EQB-Q		-	-1.1	-0.8	V	
	PDTA124EQB-Q		-	-1.1	-0.8	V	
	PDTA144EQB-Q		-	-1.2	-0.8	V	
$V_{I(on)}$	on-state input voltage						
	PDTA143EQB-Q	$V_{CE} = -0.3\ \text{V}$ ; $I_C = -20\ \text{mA}$	-2.5	-1.9	-	V	
	PDTA114EQB-Q	$V_{CE} = -0.3\ \text{V}$ ; $I_C = -10\ \text{mA}$	-2.5	-1.8	-	V	
	PDTA124EQB-Q	$V_{CE} = -0.3\ \text{V}$ ; $I_C = -5\ \text{mA}$	-2.5	-1.7	-	V	
	PDTA144EQB-Q	$V_{CE} = -0.3\ \text{V}$ ; $I_C = -2\ \text{mA}$	-3.0	-1.6	-	V	
R1	bias resistor 1 (input)						
	PDTA143EQB-Q		[1]	3.3	4.7	6.1	k $\Omega$
	PDTA114EQB-Q		7	10	13	k $\Omega$	
	PDTA124EQB-Q		15.4	22	28.6	k $\Omega$	
	PDTA144EQB-Q		33	47	61	k $\Omega$	
R2/R1	bias resistor ratio		0.8	1	1.2		
$f_T$	transition frequency	$V_{CE} = -5\ \text{V}$ ; $I_C = -10\ \text{mA}$ ; $f = 100\ \text{MHz}$	[2]	-	180	-	MHz
$C_C$	collector capacitance	$V_{CB} = -10\ \text{V}$ ; $I_E = I_C = 0\ \text{A}$ ; $f = 1\ \text{MHz}$	-	-	3	pF	

[1] See "Section 11: Test information" for resistor calculation and test conditions

[2] Characteristics of built-in transistor

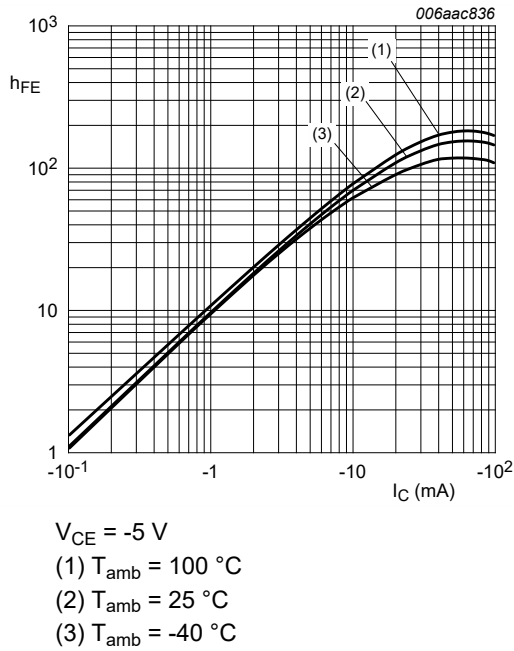


Fig. 4. PDTA143EQB-Q: DC current gain as a function of collector current; typical values

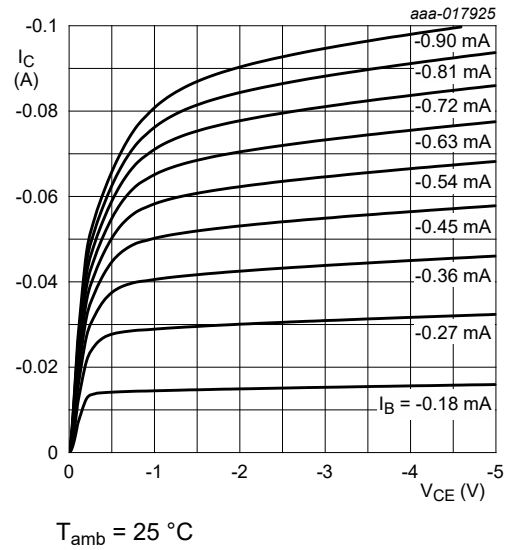


Fig. 5. PDTA143EQB-Q: Collector current as a function of collector-emitter voltage; typical values

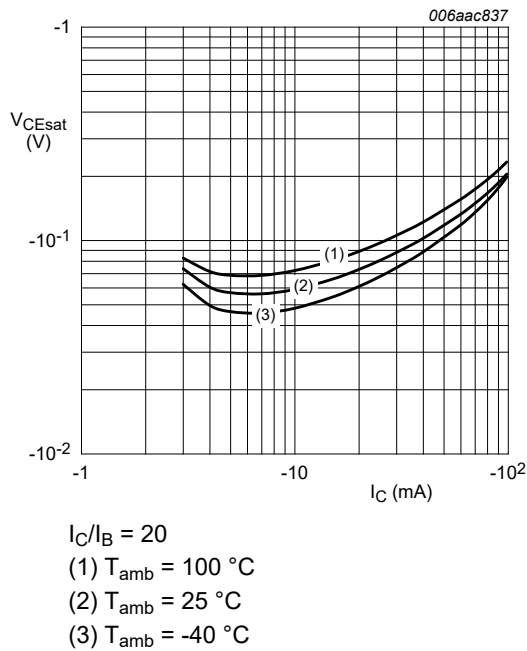


Fig. 6. PDTA143EQB-Q: Collector-emitter saturation voltage as a function of collector current; typical values

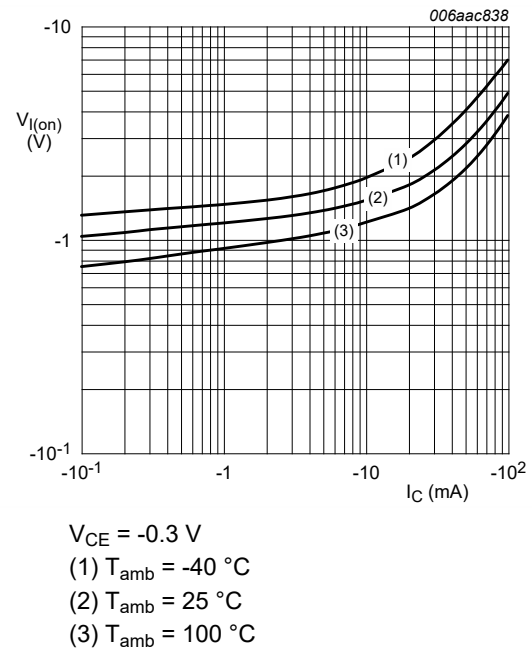
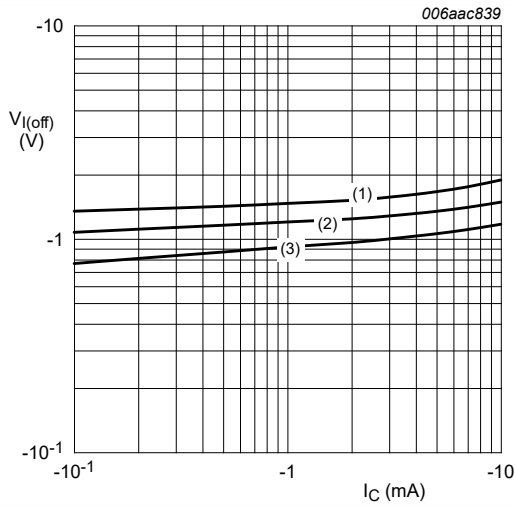
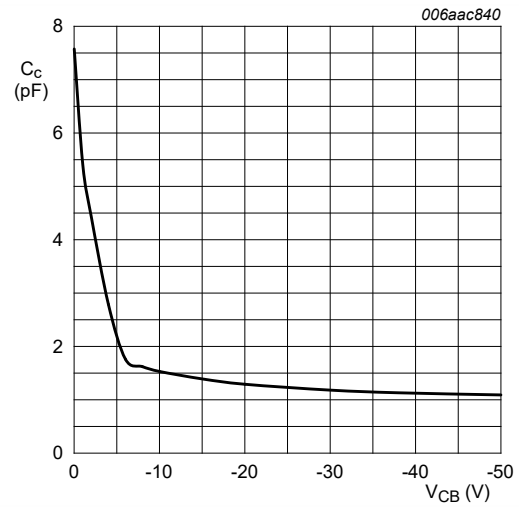


Fig. 7. PDTA143EQB-Q: On-state input voltage as a function of collector current; typical values



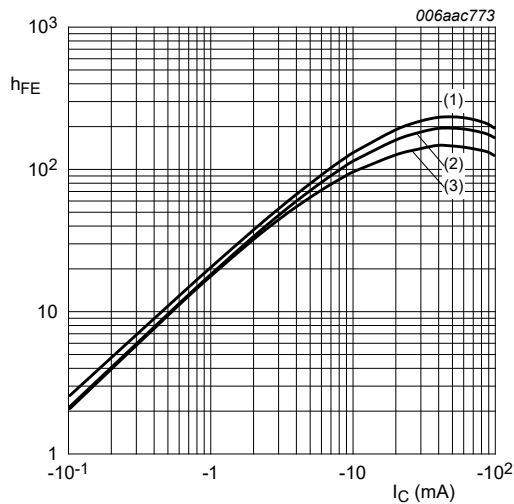
$V_{CE} = -5\text{ V}$   
 (1)  $T_{amb} = -40^\circ\text{C}$   
 (2)  $T_{amb} = 25^\circ\text{C}$   
 (3)  $T_{amb} = 100^\circ\text{C}$

Fig. 8. PDTA143EQB-Q: Off-state input voltage as a function of collector current; typical values



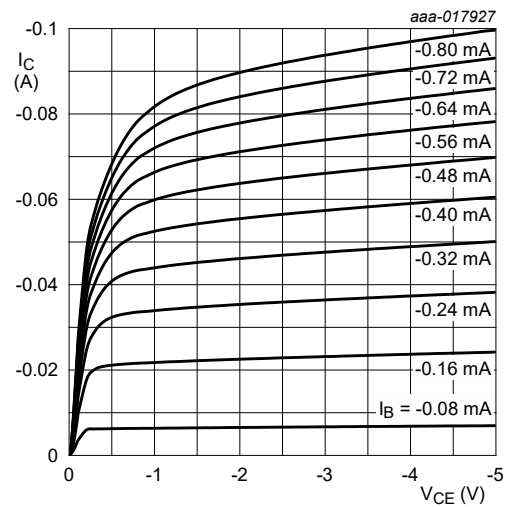
$f = 1\text{ MHz}$   
 $T_{amb} = 25^\circ\text{C}$

Fig. 9. PDTA143EQB-Q: Collector capacitance as a function of collector-base voltage; typical values



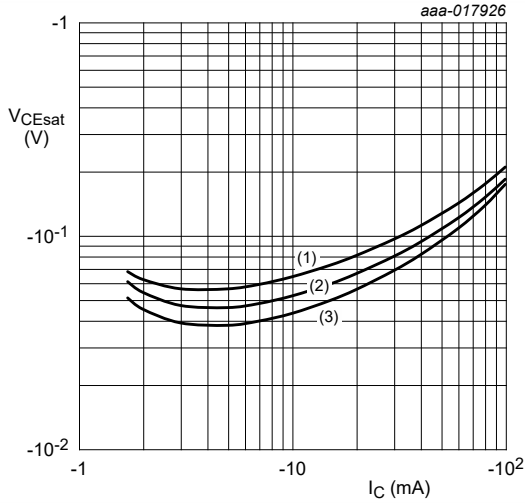
$V_{CE} = -5\text{ V}$   
 (1)  $T_{amb} = 100^\circ\text{C}$   
 (2)  $T_{amb} = 25^\circ\text{C}$   
 (3)  $T_{amb} = -40^\circ\text{C}$

Fig. 10. PDTA114EQB-Q: DC current gain as a function of collector current; typical values



$T_{amb} = 25^\circ\text{C}$

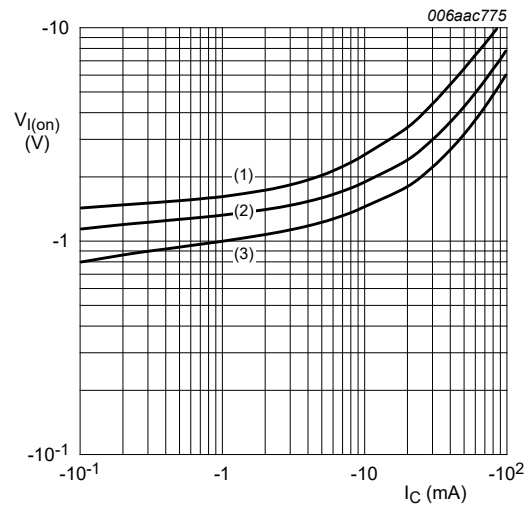
Fig. 11. PDTA114EQB-Q: Collector current as a function of collector-emitter voltage; typical values



$I_C/I_B = 20$

- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -40\text{ °C}$

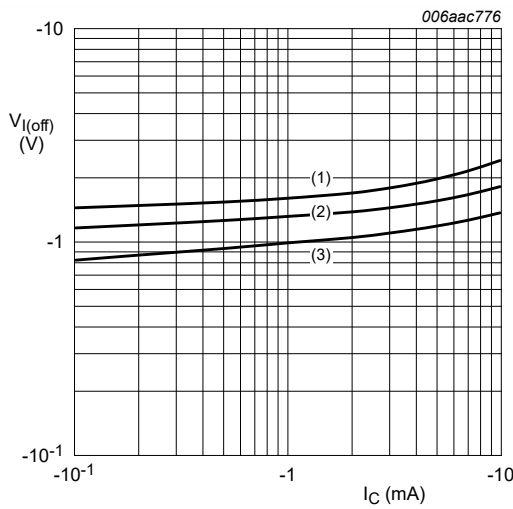
**Fig. 12. PDTA114EQB-Q: Collector-emitter saturation voltage as a function of collector current; typical values**



$V_{CE} = -0.3\text{ V}$

- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = 100\text{ °C}$

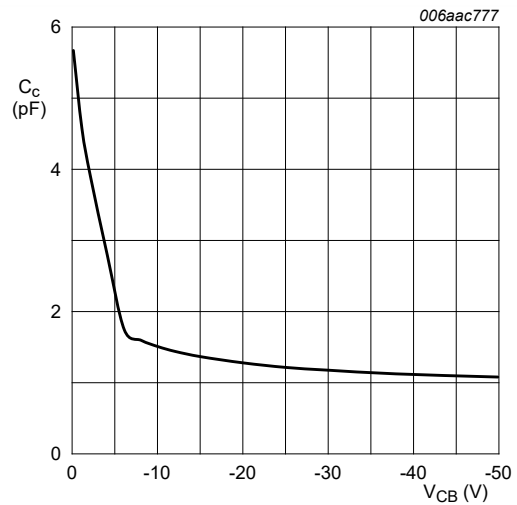
**Fig. 13. PDTA114EQB-Q: On-state input voltage as a function of collector current; typical values**



$V_{CE} = -5\text{ V}$

- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = 100\text{ °C}$

**Fig. 14. PDTA114EQB-Q: Off-state input voltage as a function of collector current; typical values**



$f = 1\text{ MHz}$

$T_{amb} = 25\text{ °C}$

**Fig. 15. PDTA114EQB-Q: Collector capacitance as a function of collector-base voltage; typical values**



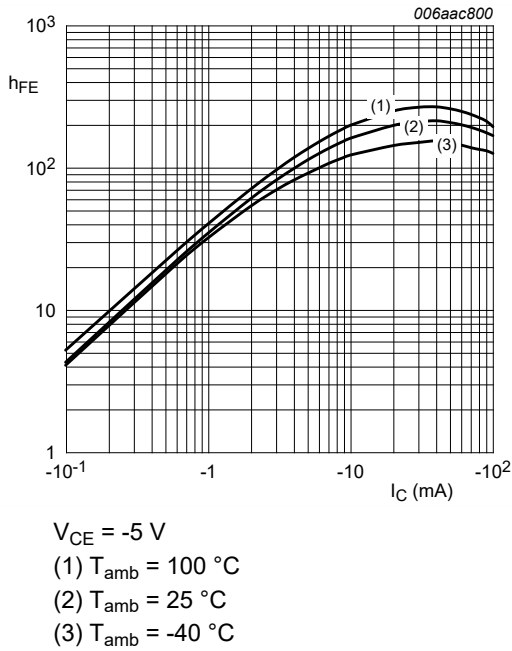


Fig. 16. PDTA124EQB-Q: DC current gain as a function of collector current; typical values

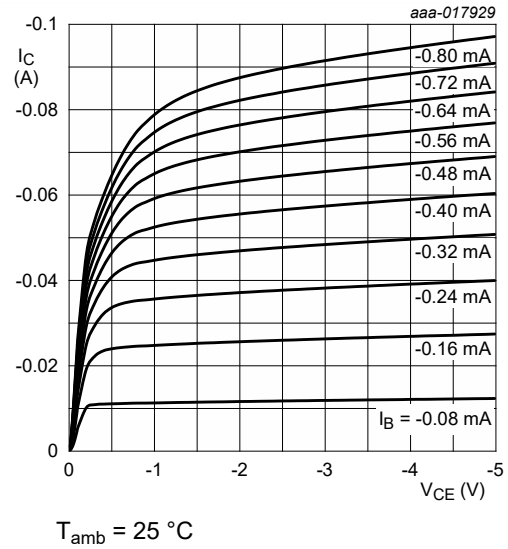


Fig. 17. PDTA124EQB-Q: Collector current as a function of collector-emitter voltage; typical values

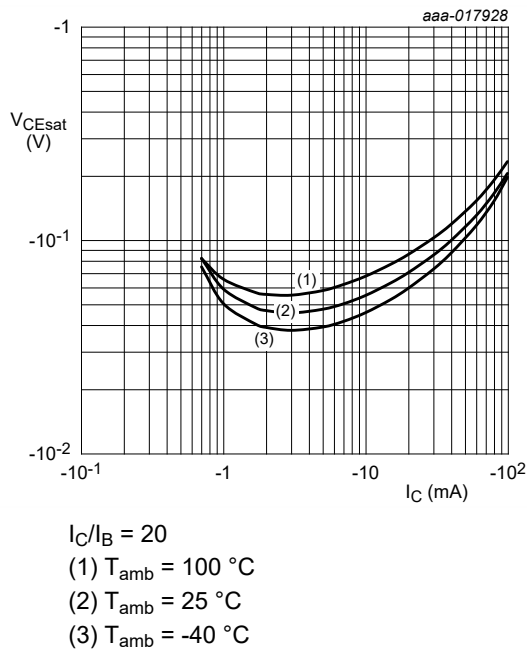


Fig. 18. PDTA124EQB-Q: Collector-emitter saturation voltage as a function of collector current; typical values

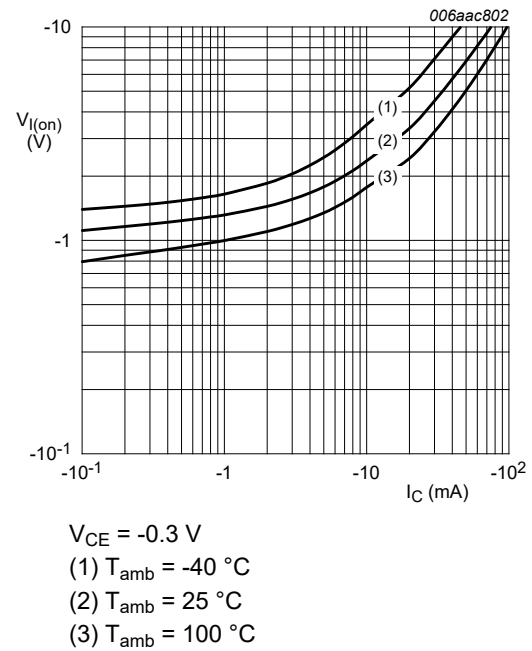
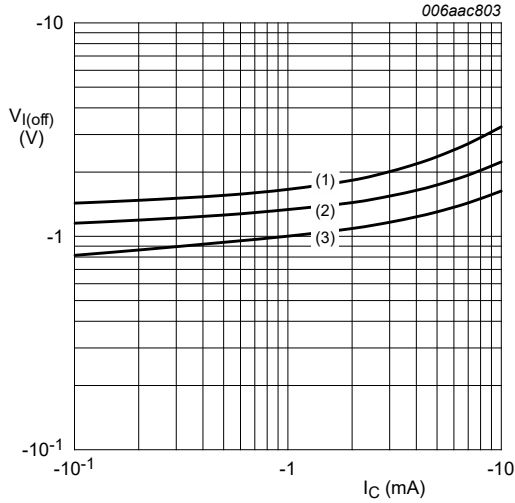
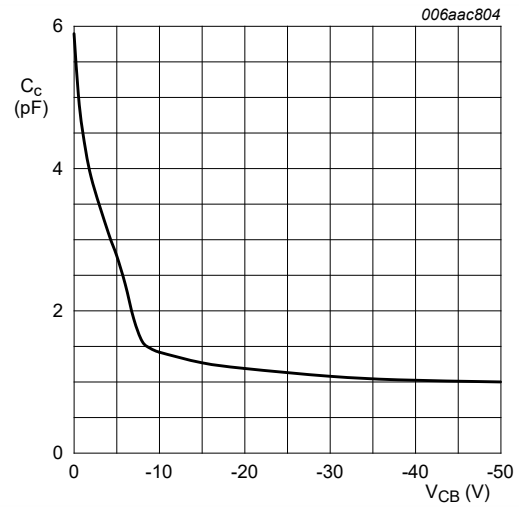


Fig. 19. PDTA124EQB-Q: On-state input voltage as a function of collector current; typical values



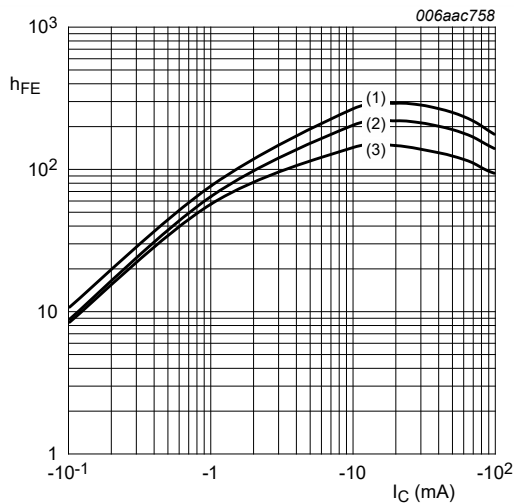
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = -40 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = 100 \text{ }^\circ\text{C}$

Fig. 20. PDTA124EQB-Q: Off-state input voltage as a function of collector current; typical values



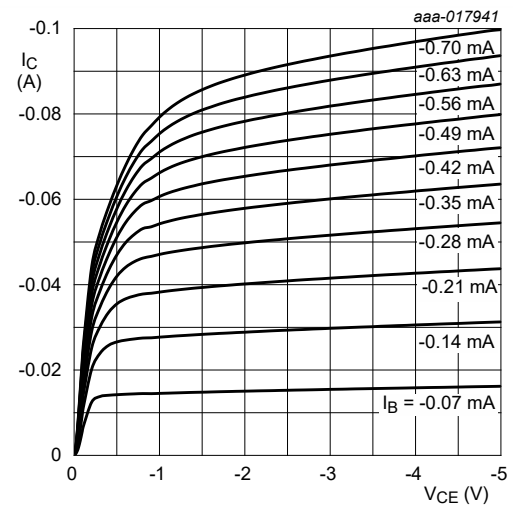
$f = 1 \text{ MHz}$   
 $T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 21. PDTA124EQB-Q: Collector capacitance as a function of collector-base voltage; typical values



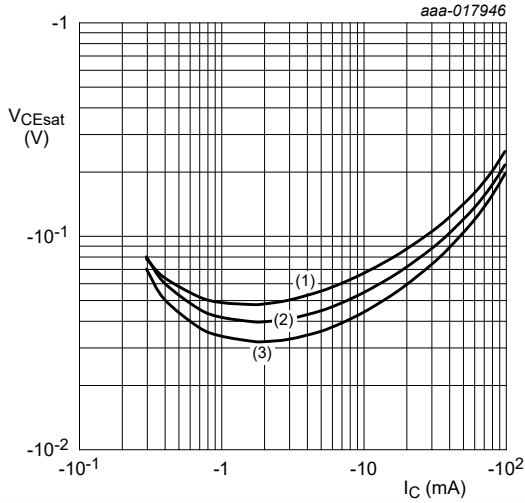
$V_{CE} = -5 \text{ V}$   
 (1)  $T_{amb} = 100 \text{ }^\circ\text{C}$   
 (2)  $T_{amb} = 25 \text{ }^\circ\text{C}$   
 (3)  $T_{amb} = -40 \text{ }^\circ\text{C}$

Fig. 22. PDTA144EQB-Q: DC current gain as a function of collector current; typical values



$T_{amb} = 25 \text{ }^\circ\text{C}$

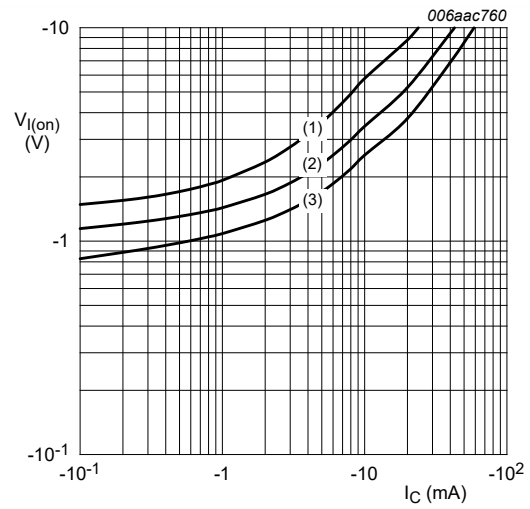
Fig. 23. PDTA144EQB-Q: Collector current as a function of collector-emitter voltage; typical values



$I_C/I_B = 20$

- (1)  $T_{amb} = 100\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = -40\text{ °C}$

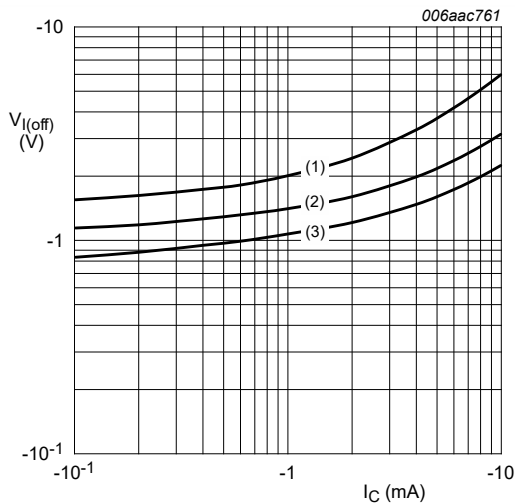
**Fig. 24. PDTA144EQB-Q: Collector-emitter saturation voltage as a function of collector current; typical values**



$V_{CE} = -0.3\text{ V}$

- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = 100\text{ °C}$

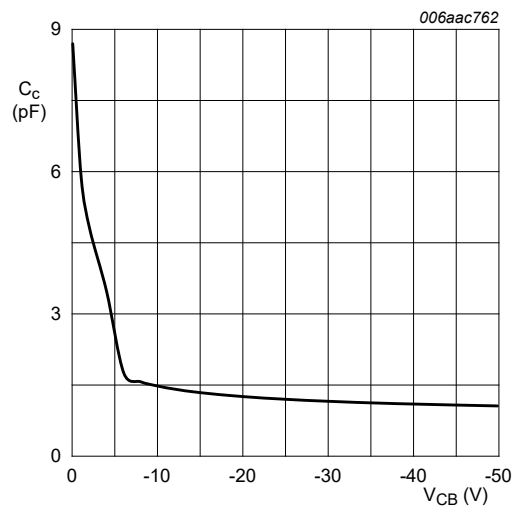
**Fig. 25. PDTA144EQB-Q: On-state input voltage as a function of collector current; typical values**



$V_{CE} = -5\text{ V}$

- (1)  $T_{amb} = -40\text{ °C}$
- (2)  $T_{amb} = 25\text{ °C}$
- (3)  $T_{amb} = 100\text{ °C}$

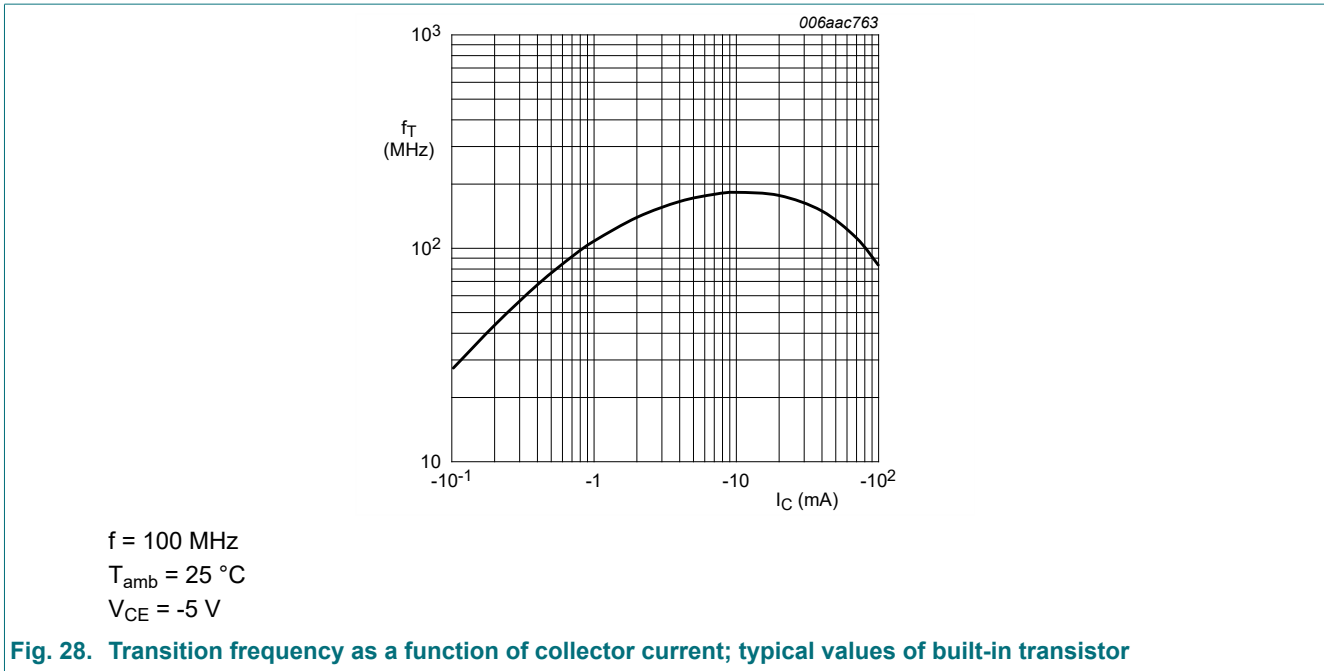
**Fig. 26. PDTA144EQB-Q: Off-state input voltage as a function of collector current; typical values**



$f = 1\text{ MHz}$

$T_{amb} = 25\text{ °C}$

**Fig. 27. PDTA144EQB-Q: Collector capacitance as a function of collector-base voltage; typical values of built-in transistor**



## 11. Test information

### Resistor calculation

- Calculation of bias resistor 1 (R1)

$$R1 = \frac{V(I12) - V(I11)}{I12 - I11}$$

- Calculation of bias resistor ratio (R2/R1)

$$\frac{R2}{R1} = \frac{V(I14) - V(I13)}{R1 \cdot (I14 - I13)} - 1$$

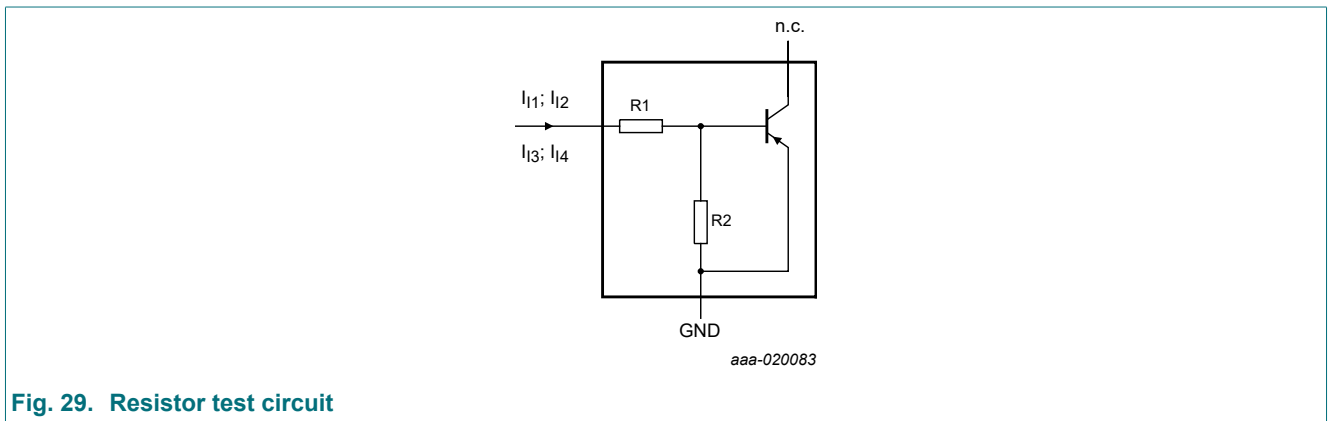


Fig. 29. Resistor test circuit

### Resistor test conditions

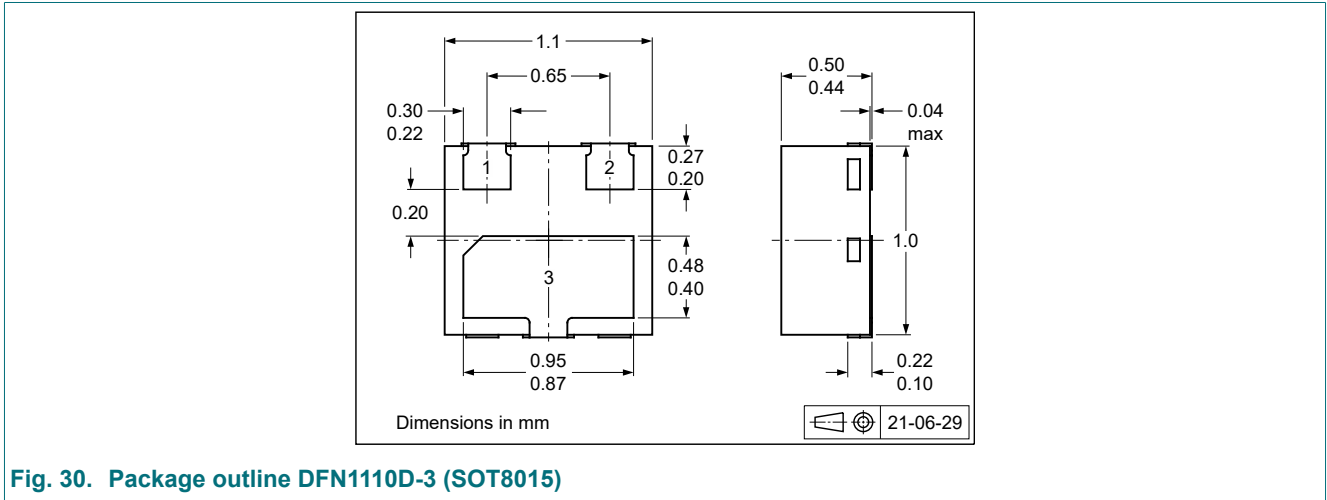
Table 9. Resistor test conditions

Type number	R1 (kΩ)	R2 (kΩ)	Test conditions			
			I <sub>11</sub>	I <sub>12</sub>	I <sub>13</sub>	I <sub>14</sub>
PDTA143EQB-Q	4.7	4.7	-600 μA	-700 μA	600 μA	700 μA
PDTA114EQB-Q	10	10	-350 μA	-450 μA	350 μA	450 μA
PDTA124EQB-Q	22	22	-150 μA	-230 μA	150 μA	230 μA
PDTA144EQB-Q	47	47	-55 μA	-105 μA	55 μA	105 μA

### 11.1. Quality information

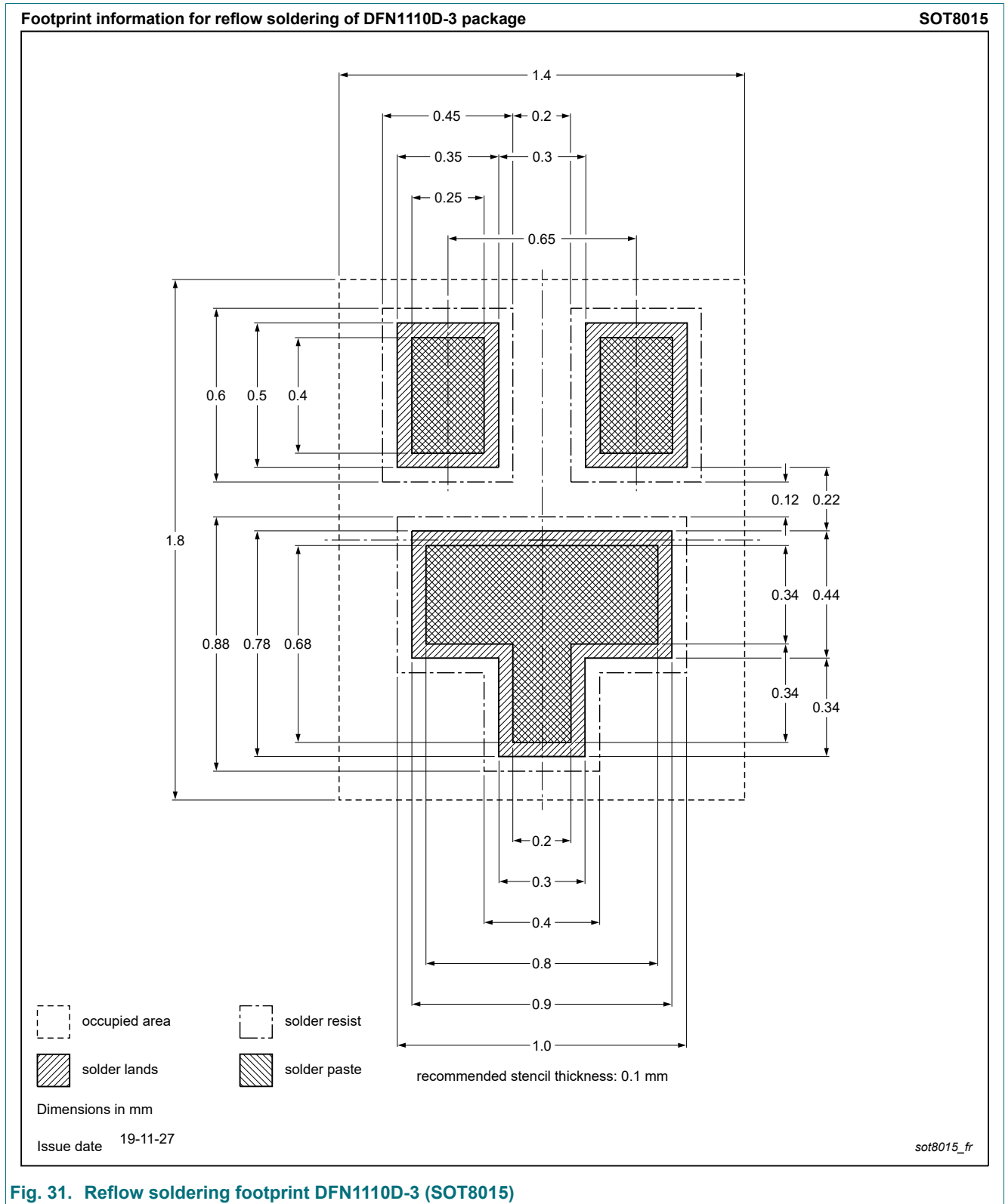
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

## 12. Package outline



**Fig. 30. Package outline DFN1110D-3 (SOT8015)**

### 13. Soldering



**Fig. 31. Reflow soldering footprint DFN1110D-3 (SOT8015)**

## 14. Revision history

Table 10. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PDTA143_114_124_144EQB-Q_SER v.1	20210928	Product data sheet	-	-



## 15. Legal information

### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

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